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Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt® G5



| PRIMARY CHARACTERISTICS | | | | | | |
|--|-------------|--|--|--|--|--|
| I _{F(AV)} | 30 A | | | | | |
| V_{R} | 600 V | | | | | |
| V _F at I _F at 125 °C | 1.15 V | | | | | |
| t _{rr} (typ.) | 25 | | | | | |
| I _{FSM} | 330 | | | | | |
| T _J max. | 175 °C | | | | | |
| Package | TO-247AD 2L | | | | | |
| Circuit configuration | Single | | | | | |

FEATURES

- · Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



• 175 °C maximum operating junction temperature



 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



ROHS COMPLIANT HALOGEN FREE

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|-----------------------------------|---|-------------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Repetitive peak reverse voltage | V _{RRM} | | 600 | V | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 123 °C, D = 0.50 | 30 | | | | |
| Non-repetitive peak surge current | I _{FSM} | $T_C = 25$ °C, $t_p = 10$ ms, sine wave | 330 | Α | | | |
| Repetitive peak forward current | I _{FRM} | T _C = 123 °C, D = 0.50, f = 20 kHz | 60 | | | | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|-----------------|--|------------------------------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Breakdown voltage, blocking voltage | V_{BR}, V_{R} | I _R = 100 μA | 600 | - | - | | |
| Forward voltage | V | I _F = 30 A | - | 1.3 | 1.6 | V | |
| | V _F | I _F = 30 A, T _J = 125 °C | - | 1.15 | - | | |
| Reverse leakage current | I _R | $V_R = V_R$ rated | - | - | 20 | | |
| neverse leakage current | | T _J = 125 °C, V _R = V _R rated | 125 °C, $V_R = V_R$ rated 50 | | 500 | μA | |
| Junction capacitance | C _T | V _R = 200 V | - | 36 | - | pF | |
| Series inductance | L _S | Measured to lead 5 mm from package body | - | 8 | - | nH | |



| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | | |
|---|------------------|--------------------------------------|---|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1.0 \text{ A}, dI_F/dt = 100$ |) A/μs, V _R = 30 V | - | 25 | - | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 41 | - | ns | |
| | | T _J = 125 °C | | - | 58 | - | 1 | |
| Dook recovery ourrent | 1 | T _J = 25 °C | $I_F = 20 \text{ A},$ $dI_F/dt = 1000 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}$ | - | 19 | - | Α | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 32 | - | | |
| Devenue vecevent eberge | Q _{rr} | T _J = 25 °C | | - | 419 | =. | nC | |
| Reverse recovery charge | | T _J = 125 °C | | - | 1176 | - | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | $I_F = 30 \text{ A},$ $dI_F/dt = 1000 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}$ | - | 46 | - | ns | |
| neverse recovery time | | T _J = 125 °C | | - | 65 | =. | | |
| Dools recovery assured | | T _J = 25 °C | | - | 21 | =. | Α | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 36 | - | | |
| Reverse recovery charge | | T _J = 25 °C | | - | 550 | - | 0 | |
| | Q _{rr} | T _J = 125 °C | | - | 1560 | - | nC | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|-----------------------------------|-------------------------|--------------|------|------------|---|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Thermal resistance, junction-to-case | R _{thJC} | | - | - | 1.1 | °C/W | |
| Woight | | | - | 5.5 | - | g | |
| Weight | | | - | 0.2 | - | OZ. | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | $\begin{array}{c} \text{kgf} \cdot \text{cm} \\ \text{(lbf} \cdot \text{in)} \end{array}$ | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C | |
| Marking device | | Case style: TO-247AD 2L | E5PH3006L | | | | |

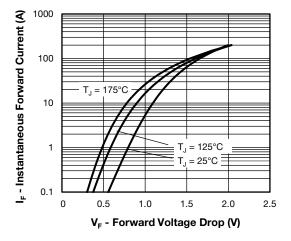


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

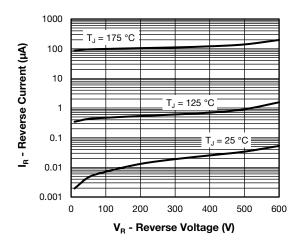


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg



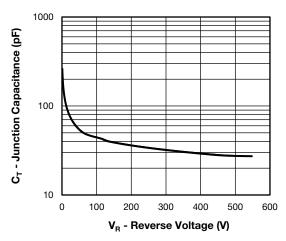


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

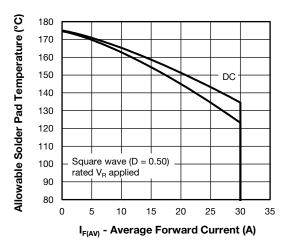


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

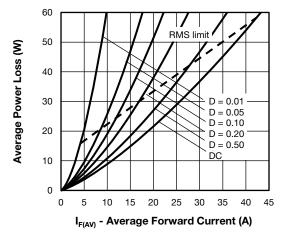


Fig. 5 - Forward Power Loss Characteristics, Per Leg

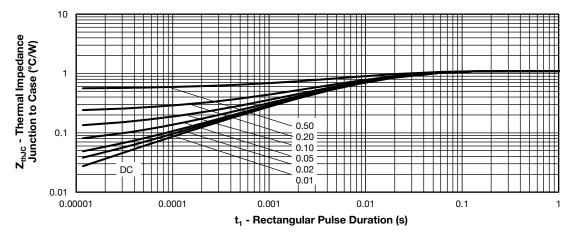


Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg



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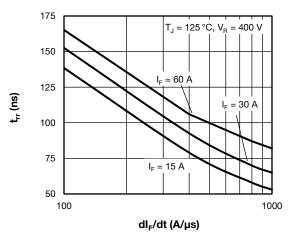


Fig. 7 - Typical Reverse Recovery Time vs. dl_E/dt, Per Leg

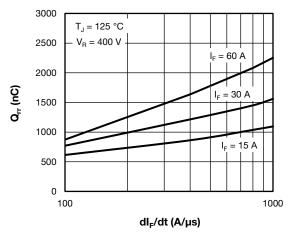


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

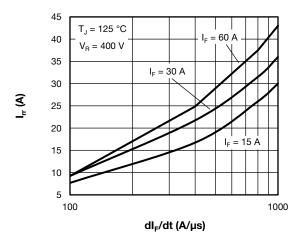


Fig. 9 - Typical Reverse Recovery Current vs. dI_F/dt , Per Leg

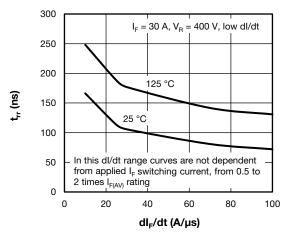


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

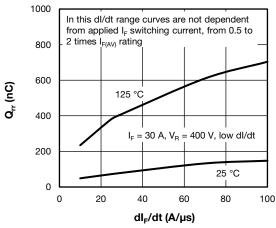


Fig. 11 - Typical Reverse Recovery Charge vs. dI_F/dt , Per Leg

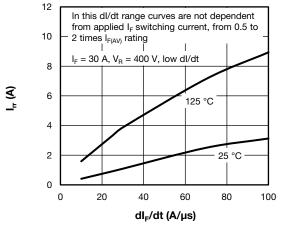


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

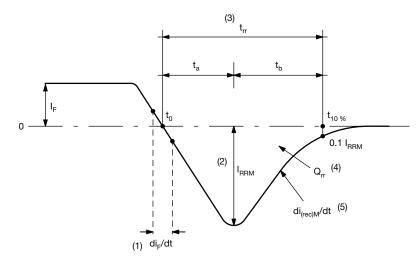


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

(1) di_E/dt - rate of change of current through zero crossing

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- $^{(2)}$ I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ $\,Q_{rr}$ area under curve defined by t_0 and $t_{10\,\%}$

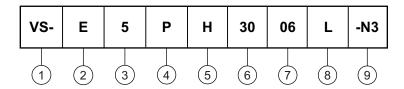
$$Q_{rr} = \int_{t_0}^{\tau_{10} \%} I(t) dt$$

 $^{(5)}$ $di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - E = single diode

3 - 5 = Fred generation 5

4 - Package:

P = TO-247 package

H = hyperfast recovery

6 - Current rating (30 = 30 A)

7 - Voltage rating (06 = 600 V)

8 - Package: L = long lead (TO-247AD)

9 - Environmental digit:

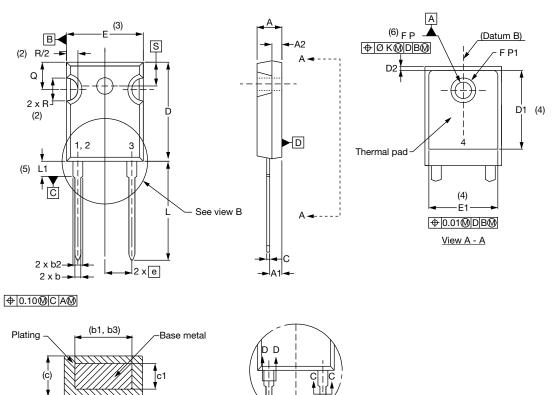
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|--|----|-----|-------------------------|--|--|--|
| PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | |
| VS-E5PH3006L-N3 | 25 | 500 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|--|--------------------------|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?95536</u> | | | | | |
| Part marking information | www.vishay.com/doc?95648 | | | | |

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

| SYMBOL | MILLIN | LIMETERS | | HES | NOTES |
|----------|--------|----------|-------|-------|-------|
| STIVIDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.65 | 5.31 | 0.183 | 0.209 | |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | |
| A2 | 1.50 | 2.49 | 0.059 | 0.098 | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | |
| b3 | 1.65 | 2.34 | 0.065 | 0.092 | |
| С | 0.38 | 0.89 | 0.015 | 0.035 | |
| c1 | 0.38 | 0.84 | 0.015 | 0.033 | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 |
| D1 | 13.08 | - | 0.515 | - | 4 |
| D2 | 0.51 | 1.35 | 0.020 | 0.053 | |

Section C - C, D - D

| SYMBOL | MILLIN | IETERS | INC | INCHES | | |
|---------|----------|--------|-----------|--------|-------|--|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Е | 15.29 | 15.87 | 0.602 | 0.625 | 3 | |
| E1 | 13.46 | - | 0.53 | - | | |
| е | 5.46 | BSC | 0.215 | BSC | | |
| ØK | 0.2 | 254 | 0.010 | | | |
| L | 19.81 | 20.32 | 0.780 | 0.800 | | |
| L1 | 3.71 | 4.29 | 0.146 | 0.169 | | |
| ØΡ | 3.56 | 3.66 | 0.14 | 0.144 | | |
| Ø P1 | - | 6.98 | - | 0.275 | | |
| Q | 5.31 | 5.69 | 0.209 | 0.224 | | |
| R | 4.52 | 5.49 | 0.178 | 0.216 | | |
| S | 5.51 BSC | | 0.217 BSC | | | |
| | • | | • | • | | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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